## Amendments to the Claims:

This listing of claims will replace all prior versions and listings of claims in the application:

## **Listing of Claims:**

- 1. 56. (Cancelled).
- 57. (Previously Presented) A plurality of carbon nanosheets on a substrate, each of the plurality of carbon nanosheets having a thickness of 2 nanometers or less, wherein the plurality of carbon nanosheets are aligned and stand on their edges roughly vertically to the substrate.
  - 58. (Previously Presented) The plurality of carbon nanosheets of claim 57, wherein: the thickness is 1 nanometer or less; and each of the plurality of carbon nanosheets comprises one to three graphene layers.
- 59. (Previously Presented) The plurality of carbon nanosheets of claim 58, wherein each of the plurality of carbon nanosheets comprises a single graphene layer.
  - 60. (Previously Presented) The plurality of carbon nanosheets of claim 57, wherein:

the specific surface area of the each of the plurality of carbon nanosheets is between 1000  $\text{m}^2/\text{g}$  to 2600  $\text{m}^2/\text{g}$ ;

each of the plurality of carbon nanosheets has a height between 100 nm and 8  $\mu m$ ; and the plurality of carbon nanosheets are in substantially pure form.

- 61. (Cancelled).
- 62. (Previously Presented) A composition comprising a plurality of carbon nanoflakes having a specific surface area between 1000 m<sup>2</sup>/g and 2600 m<sup>2</sup>/g, wherein the carbon nanoflakes are aligned, freestanding and stand on their edges roughly vertically to a substrate.

- 63. (Previously Presented) The composition of claim 62, wherein each of the plurality of carbon nanoflakes has a thickness of 10 nanometers or less.
  - 64. (Previously Presented) The composition of claim 63, wherein:
    each of the plurality of carbon nanoflakes has a thickness of 2 nanometers or less; and

the specific surface area of the each of the plurality of carbon nanoflakes is between 2000  $\,$  m $^2$ /g and 2600  $\,$  m $^2$ /g.

- 65. (Withdrawn) A method of making carbon nanoflakes comprising forming the nanoflakes on a substrate using RF-PECVD, wherein the carbon nanoflakes are aligned, freestanding and stand on their edges roughly vertically to the substrate and have a specific surface area between  $1000 \text{ m}^2/\text{g}$  and  $2600 \text{ m}^2/\text{g}$ .
- 66. (Withdrawn) The method of claim 65, wherein RF-PECVD is inductively or capacitively coupled.
  - 67. (Withdrawn) The method of claim 65, further comprising:

increasing the substrate temperature during nucleation phase of carbon nanoflake synthesis to form carbon nanosheets comprising a single graphene layer; and

attaching a grounding electrode to the substrate during a nucleation phase of nanoflake formation on the substrate.

68. (Withdrawn) The method of claim 65, wherein:

the substrate temperature is between 550 °C and 950 °C;

the PECVD chamber pressure is between 50 mTorr and 200 mTorr; and

PECVD plasma power is equal to or greater than 700 W.

- 69. (Withdrawn) The method of claim 65, wherein the CVD source gas comprises methane or acetylene, such that the CVD source gas contains a methane to hydrogen ratio between 0.05:99.95 and 100:0, or an acetylene to hydrogen ratio between 0.05:99.95 and 60:40.
  - 70. (Withdrawn) A method of making carbon nanosheets, comprising:

forming the nanosheets on a substrate, wherein the carbon nanosheets are aligned and stand on their edges roughly vertically to the substrate; and

increasing the substrate temperature during a nucleation phase of carbon nanosheet formation.

- 71. (Withdrawn) The method of claim 70, wherein inductively or capacitively coupled RF-PECVD is used to form the nanosheets.
- 72. (Withdrawn) The method of claim 70, further comprising attaching a grounding electrode to the substrate during a nucleation phase of nanoflake formation on the substrate.
  - 73. (Withdrawn) The method of claim 70, wherein:

the substrate temperature is between 550 °C and 950 °C;

the PECVD chamber pressure is between 50 mTorr and 200 mTorr; and

PECVD plasma power is equal to or greater than 700 W.

- 74. (Withdrawn) The method of claim 70, wherein the CVD source gas comprises methane or acetylene, such that the CVD source gas contains a methane to hydrogen ratio between 0.05:99.95 and 100:0, or an acetylene to hydrogen ratio between 0.05:99.95 and 60:40.
- 75. (Previously Presented) An article comprising the plurality of carbon nanosheets of claim 57, wherein the article is selected from a group consisting of a field emitter, a catalyst

support, a hydrogen storage device, a sensor, a blackbody absorber, a composite material, and a coating.

76. (Previously Presented) An article comprising the plurality of carbon nanosheets of claim 62, wherein the article is selected from a group consisting of a field emitter, a catalyst support, a hydrogen storage device, a sensor, a blackbody absorber, a composite material, and a coating.

## 77. - 78. (Cancelled).

- 79. (New) The plurality of carbon nanosheets of claim 57, wherein the carbon nanosheets comprise crystalline carbon nanosheets.
- 80. (New) The plurality of carbon nanosheets of claim 62, wherein the carbon nanosheets comprise crystalline carbon nanosheets.